12 V, 2 A Logic Controlled High-Side Power Switch

Data Sheet **ADP1290**

FEATURES

- Low RDS_{ON} of 40 mΩ
- Wide input voltage range: 2.3 V to 13.2 V
- 2 A continuous operating current, T_J = <85°C
- 1.2 V logic compatible enable input
- Low 15 µA quiescent current, V_{IN} = 3.3 V
- Low 19 µA quiescent current, V_{IN} = 6.5 V
- Ultralow shutdown current: 2.0 µA at V_{IN} = 6.5 V
- Ultrasmall 1.0 mm × 1.5 mm, 6-ball, 0.5 mm pitch WLCSP

APPLICATIONS

- Mobile phones
- Digital cameras and audio devices
- Portable and battery-powered equipment

TYPICAL APPLICATIONS CIRCUIT

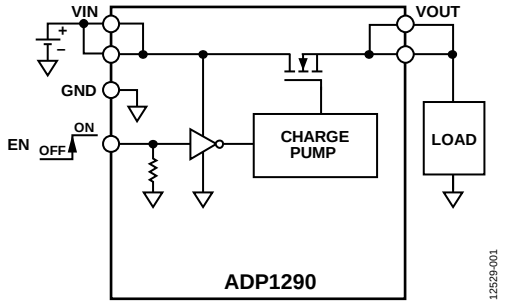


Figure 1.

GENERAL DESCRIPTION

The ADP1290 is a high-side load switch designed for operation between 2.3 V and 13.2 V. This load switch provides power domain isolation, helping to extend battery operation. The device contains a low on-resistance, N-channel MOSFET that supports more than 2 A of continuous current and minimizes power loss. In addition, RDS_{ON} is constant independent of the VIN voltage. The low 15 µA quiescent current and ultralow shutdown current of 20 µA make the ADP1290 ideal for battery-operated portable equipment. The built-in level shifter for enable logic makes the ADP1290 compatible with many processors and general-purpose input/output (GPIO) controllers.

In addition to operating performance, the ADP1290 occupies minimal printed circuit board (PCB) space with an area of less than 1.5 mm^2 and a height of 0.60 mm.

The ADP1290 is available in an ultrasmall, 1 mm × 1.5 mm, 6-ball, 0.5 mm pitch WLCSP.

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REVISION HISTORY

12/14—Revision 0: Initial Version

SPECIFICATIONS

V_{IN} = 6.5 V, enable input voltage (V_{EN}) = V_{IN}, I_{OUT} = 2 A, T_A = 25°C, T_J = −40°C to +105°C for minimum/maximum specifications, unless otherwise noted.

Table 1.

Parameter	Symbol	Test Conditions/Comments	Min	Typ	Max	Unit
INPUT VOLTAGE RANGE	V_{IN}		2.3		13.2	V
EN INPUT		V_{IN} = 2.3 V to 13.2 V				
EN Input	V_{IH}		1.0			V
	V_{IL}				0.4	V
EN Input Pull-Down Current	I_{EN}			15	1000	nA
CURRENT						
Ground (Quiescent) Current	I_{GND}	V_{IN} = 2.3 V		10	30	µA
		V_{IN} = 3.3 V		15	45	µA
		V_{IN} = 6.5 V		19	45	µA
		V_{IN} = 13.2 V		20	45	µA
Shutdown Current	I_{OFF}	V_{EN} = 0 V, V_{IN} = 6.5 V, output = high impedance			2.0	µA
		V_{EN} = 0 V, output voltage (V_{OUT}) = 0 V, V_{IN} = 2.3 V to 13.2 V			4.0	µA
Continuous Operating Current	I_{OUT}	V_{IN} = 2.3 V to 13.2 V, T_J = <85°C		2		A
VIN TO VOUT RESISTANCE	RDS_{ON}					
		V_{IN} = 2.3 V		40	70	mΩ
		V_{IN} = 3.3 V		40	70	mΩ
		V_{IN} = 6.5 V		40	70	mΩ
		V_{IN} = 13.2 V		40	70	mΩ
V_{OUT} TURN ON		See Figure 2				
Turn On Delay Time	t_{ON_DLY}	V_{IN} = 5.5 V, C_{LOAD} = 10 µF		250		µs
Turn On Rise Time	t_{ON_RISE}	V_{IN} = 5.5 V, C_{LOAD} = 10 µF		350		µs
Turn On Time	t_{ON}	Turn on delay time + turn on rise time		600	2000	µs
V_{OUT} TURN OFF		See Figure 2				
Turn Off Delay Time	t_{OFF_DLY}	V_{IN} = 5.5 V, C_{LOAD} = 10 µF, I_{OUT} = 20 mA		125		µs
Turn Off Fall Time	t_{OFF_FALL}	V_{IN} = 5.5 V, C_{LOAD} = 10 µF, I_{OUT} = 20 mA		2000		µs
Turn Off Time	t_{OFF}	Turn off delay time + turn off fall time		2125		µs
SOURCE DRAIN BODY DIODE						
Diode Forward Current	I_D	V_{IN} = 0 V, pulse width = 70 µs, duty cycle < 1%, V_{OUT} = 0.9 V		4	6	A

TIMING DIAGRAM

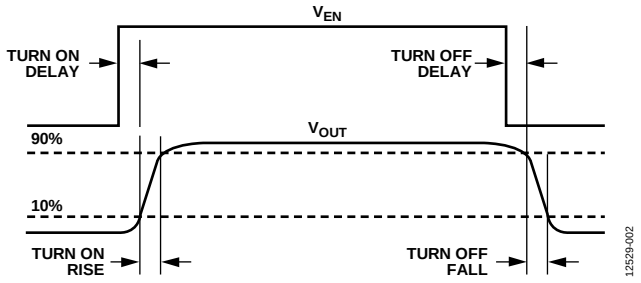


Figure 2. Timing Diagram

ABSOLUTE MAXIMUM RATINGS

Table 2.

Parameter	Rating
VIN to GND	−0.3 V to +16.5 V
VOUT to GND	−0.3 V to V_{IN}
EN to GND	−0.3 V to +16.5 V
Continuous Drain Current	
T_J = 70°C	±3 A
T_J = 105°C	±1.6 A
Continuous Diode Current	−50 mA
Storage Temperature Range	−65°C to +150°C
Operating Junction Temperature Range	−40°C to +105°C
Soldering Conditions	JEDEC J-STD-020

Stresses at or above those listed under Absolute Maximum Ratings may cause permanent damage to the product. This is a stress rating only; functional operation of the product at these or any other conditions above those indicated in the operational section of this specification is not implied. Operation beyond the maximum operating conditions for extended periods may affect product reliability.

THERMAL RESISTANCE

θ_{JA} is specified for the worst case conditions, that is, a device soldered in a circuit board for surface-mount packages.

Table 3 Thermal Resistance

Package Type	θ_{JA}	Ψ_{JB}	Unit
6-Ball, 0.5 mm Pitch WLCSP	260	58	°C/W

ESD CAUTION



ESD (electrostatic discharge) sensitive device. Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

PIN CONFIGURATION AND FUNCTION DESCRIPTIONS

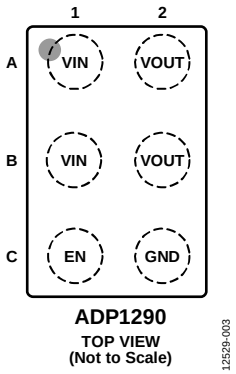


Figure 3. Pin Configuration

Table 4. Pin Function Descriptions

Pin No.	Mnemonic	Description
A1, B1	VIN	Input Voltage.
A2, B2	VOUT	Output Voltage.
C1	EN	Enable Input. Drive the EN pin high to turn on the switch. Drive the EN pin low to turn off the switch.
C2	GND	Ground.

TYPICAL PERFORMANCE CHARACTERISTICS

V_{IN} = 6.5 V, V_{EN} = V_{IN}, C_{IN} = C_{OUT} = 0 µF, T_A = 25°C, unless otherwise noted.

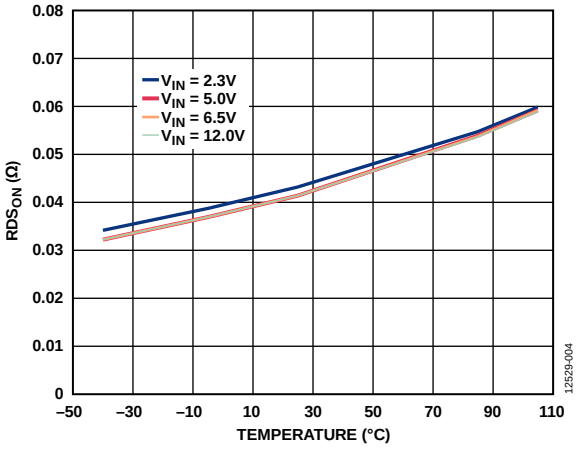


Figure 4. RDS_{ON} vs. Temperature, 50 mA, Different Input Voltages (V_{IN})

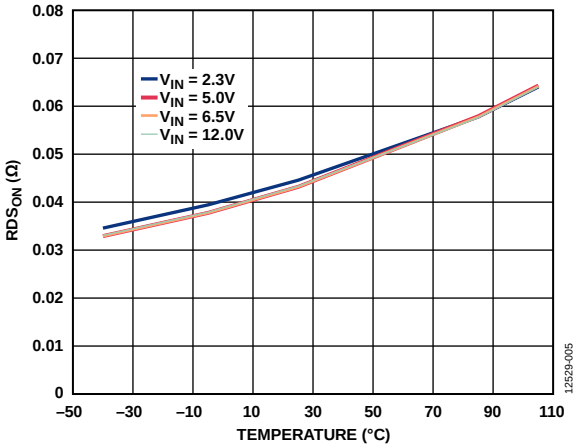


Figure 5. RDS_{ON} vs. Temperature, 2 A, Different Input Voltages (V_{IN})

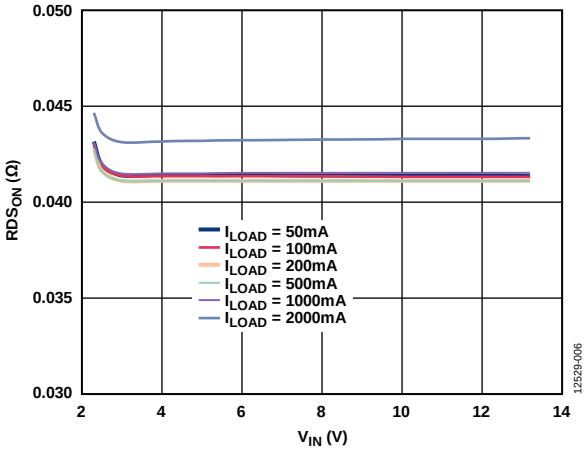


Figure 6. RDS_{ON} vs. Input Voltage (V_{IN}), Different Load Currents (I_{LOAD})

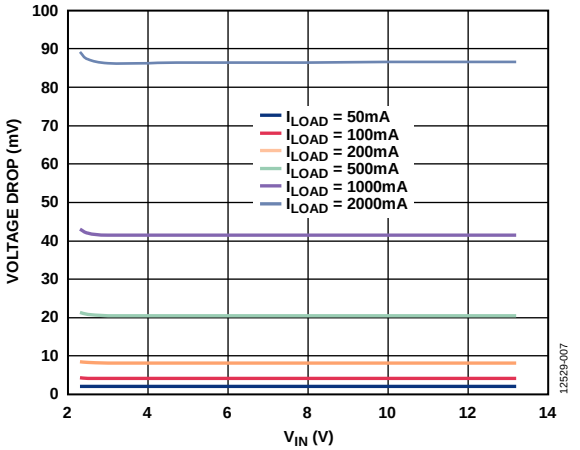


Figure 7. Voltage Drop vs. Input Voltage (V_{IN}), Different Load Currents (I_{LOAD})

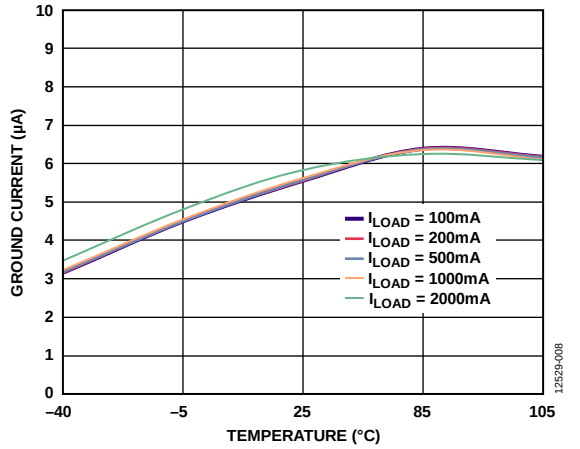


Figure 8. Ground Current vs. Temperature, Different Load Currents, V_{IN} = 2.3 V

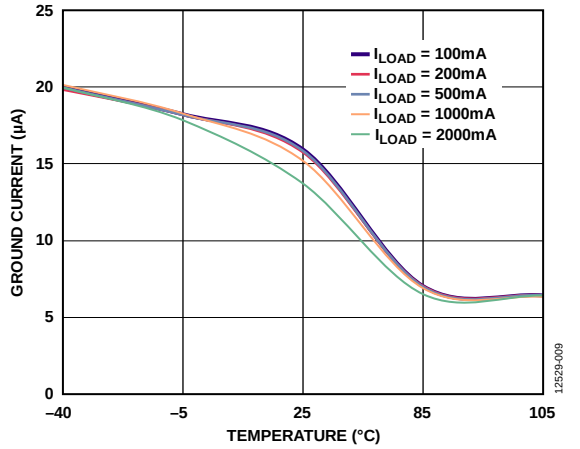


Figure 9. Ground Current vs. Temperature, Different Load Currents, V_{IN} = 6.5 V

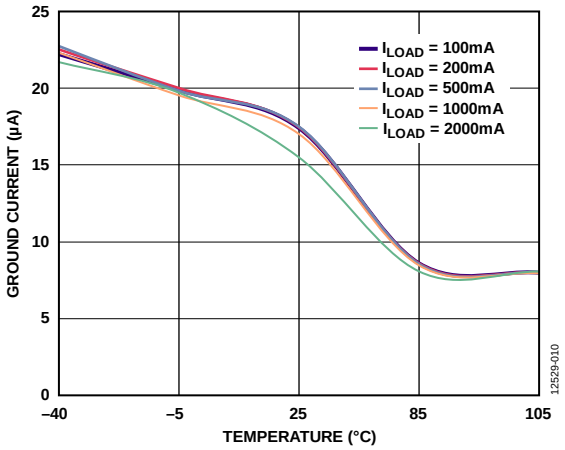


Figure 10. Ground Current vs. Temperature, Different Load Currents, V_{IN} = 13.2 V

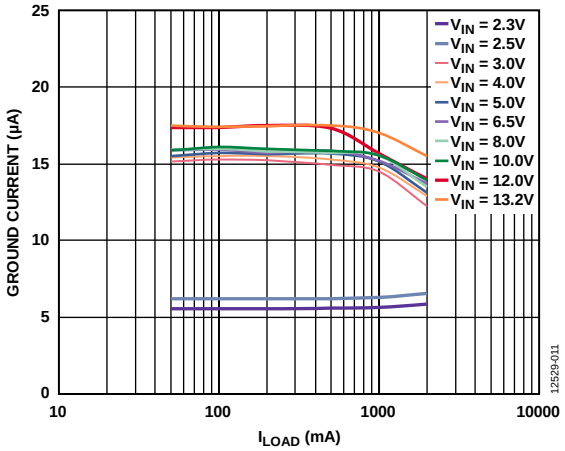


Figure 11. Ground Current vs. Load Current (I_{LOAD}), Different Input Voltages (V_{IN})

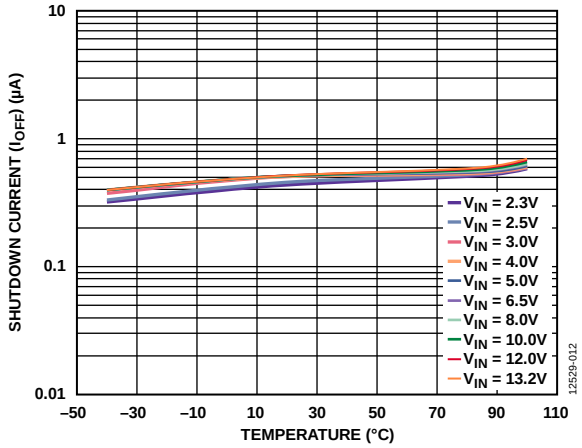


Figure 12. Ground Shutdown Current vs. Temperature, Output Open, Different Input Voltages (V_{IN})

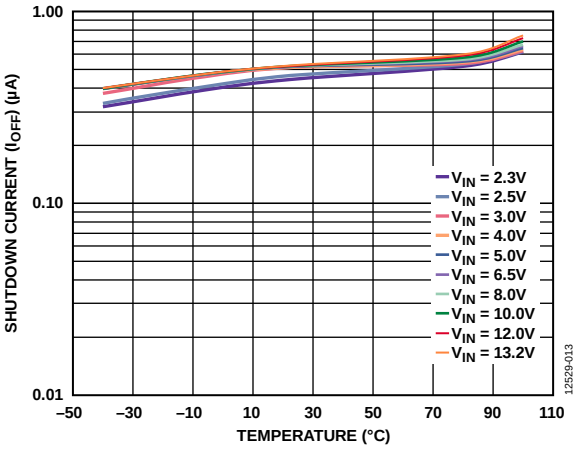


Figure 13. Ground Shutdown Current vs. Temperature, V_{OUT} = 0 V, Different Input Voltages (V_{IN})

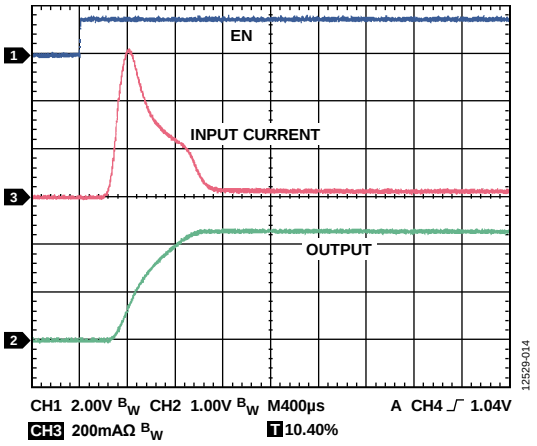


Figure 14. Typical Turn On Time and Inrush Current, V_{IN} = 2.3 V, C_{OUT} = 100 µF, R_{LOAD} = 100 Ω

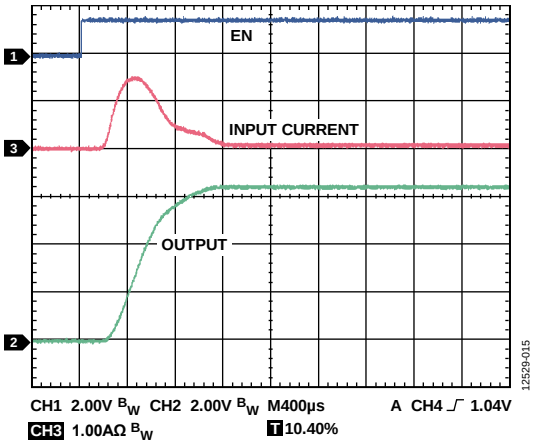


Figure 15. Typical Turn On Time and Inrush Current, V_{IN} = 6.5 V, C_{OUT} = 100 µF, R_{LOAD} = 100 Ω

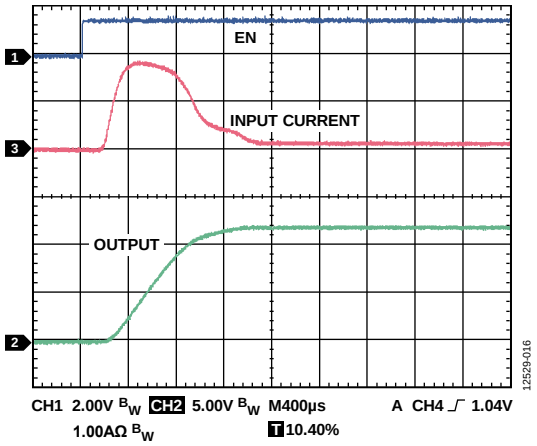


Figure 16. Typical Turn On Time and Inrush Current, V_{IN} = 13.2 V, C_{OUT} = 100 µF, R_{LOAD} = 100 Ω

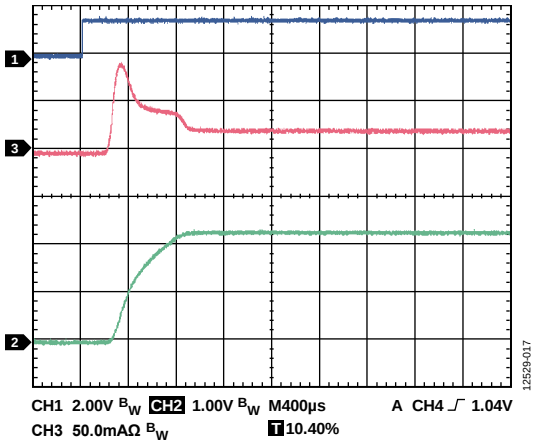


Figure 17. Typical Turn On Time and Inrush Current, V_{IN} = 2.3 V, C_{OUT} = 10 µF, R_{LOAD} = 100 Ω

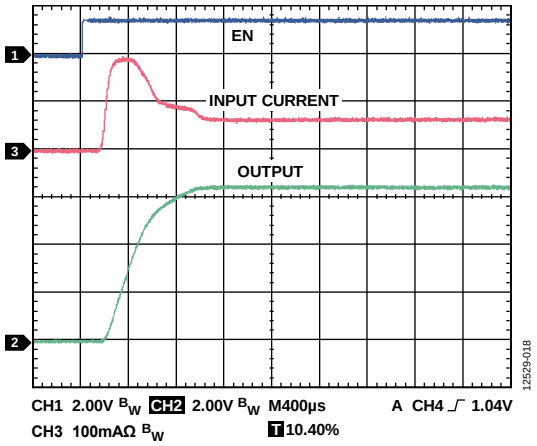


Figure 18. Typical Turn On Time and Inrush Current, V_{IN} = 6.5 V, C_{OUT} = 10 µF, R_{LOAD} = 100 Ω

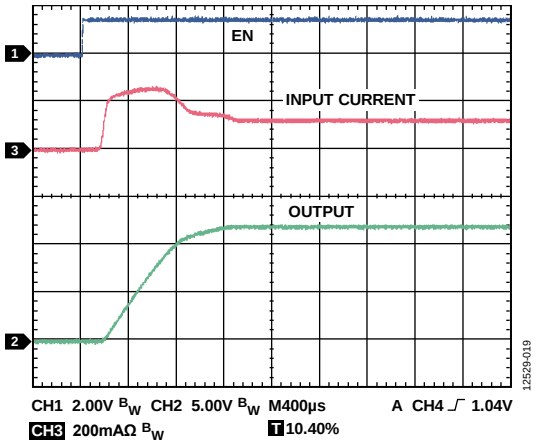


Figure 19. Typical Turn On Time and Inrush Current, V_{IN} = 13.2 V, C_{OUT} = 10 µF, R_{LOAD} = 100 Ω

THEORY OF OPERATION

The ADP1290 is a high-side NMOS load switch, controlled by an internal charge pump. The ADP1290 is designed to operate with power supply voltages between 2.3 V and 13.2 V.

An internal charge pump biases the NMOS switch to achieve a relatively constant, ultralow on resistance of 40 mΩ across the entire input voltage range. The use of the internal charge pump also allows controlled turn on times. Turning the NMOS switch on and off is controlled by the enable input, EN, which is capable of interfacing directly with 1.2 V logic signals.

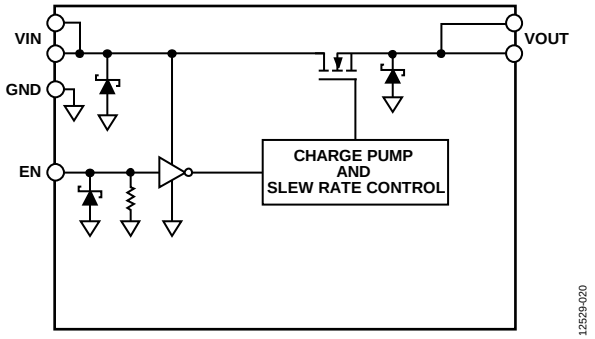


Figure 20. Functional Block Diagram

The ADP1290 is capable of 2 A of continuous current as long as T_J is less than 85°C. Between 85°C and 105°C, the rated current decreases linearly to 1.6 A.

ESD protection structures are shown in the block diagram as Zener diodes.

The ADP1290 is a low quiescent current device with a weak 15 nA pull-down current sink on its enable pin (EN).

The ADP1290 is available in a space-saving 1.0 mm × 1.5 mm, 0.5 mm pitch, 6-ball WLCSP.

APPLICATIONS INFORMATION

CAPACITOR SELECTION

Output Capacitor

The ADP1290 is designed for operation with small, space-saving ceramic capacitors but functions with most commonly used capacitors when the effective series resistance (ESR) value is carefully considered. The ESR of the output capacitor affects the response to load transients. A typical 1 µF capacitor with an ESR of 0.1 Ω or less is recommended for good transient response. Using a larger value of output capacitance improves the transient response to large changes in load current.

Input Bypass Capacitor

Connecting at least 1 µF of capacitance from VIN to GND reduces the circuit sensitivity to the PCB layout, especially when high source impedance or long input traces are encountered. When an output capacitance of greater than 1 µF is required, increase the input capacitor to match it.

GROUND CURRENT

The major source for ground current in the ADP1290 is the internal charge pump for the FET drive circuitry. Figure 21 shows the typical ground current when $V_{EN} = V_{IN}$ and varies from 2.3 V to 13.2 V.

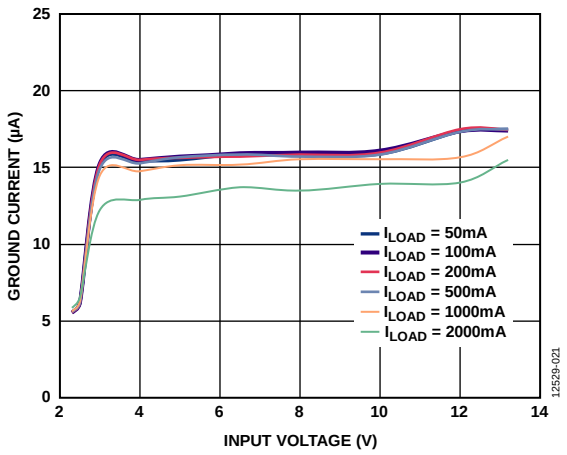


Figure 21. Ground Current vs. Input Voltage (V_{IN}), Different Load Currents (I_{LOAD})

ENABLE FEATURE

The ADP1290 uses the EN pin to enable and disable the VOUT pin under normal operating conditions. As shown in Figure 22, when a rising voltage (V_{EN}) on the EN pin crosses the active threshold, the VOUT pin turns on. When a falling voltage (V_{EN}) on the EN pin crosses the inactive threshold, the VOUT pin turns off.

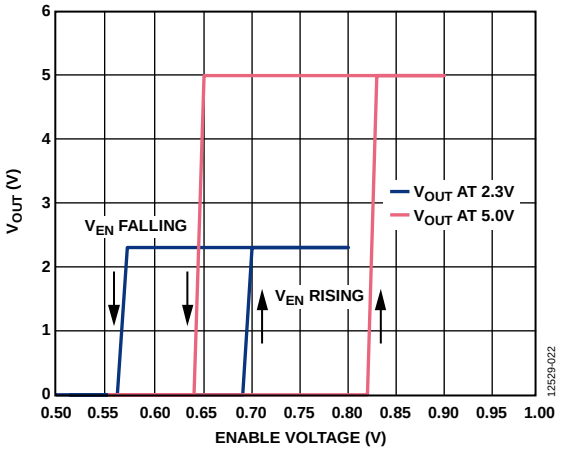


Figure 22. Typical EN Operation

As shown in Figure 22, the EN pin has hysteresis built into it. The hysteresis prevents on/off oscillations that can occur due to noise on the EN pin as it passes through the threshold points.

The EN pin rising and falling thresholds derive from the V_{IN} voltage; therefore, these thresholds vary with the changing input voltage. Figure 23 shows the typical EN rising and falling thresholds when the input voltage varies from 2.3 V to 13.2 V.

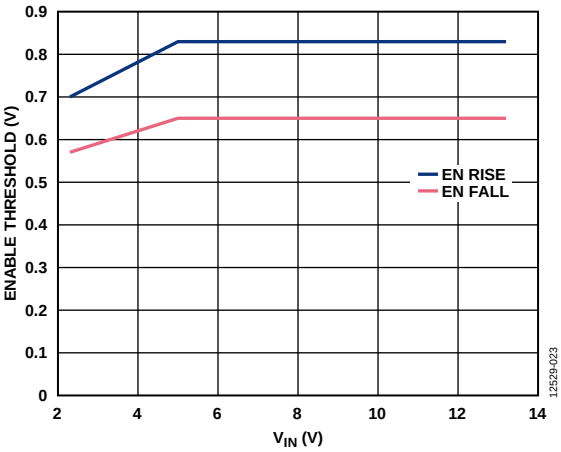


Figure 23. Typical EN Thresholds (Rising and Falling) vs. Input Voltage (V_{IN})

TIMING

Turn on delay is defined as the interval between the time that V_{EN} exceeds the rising threshold voltage and when V_{OUT} rises to ~10% of its final value. The ADP1290 includes circuitry that has a typical 250 µs turn on delay and a controlled rise time to limit the V_{IN} inrush current. As shown in Figure 24 and Figure 25, the turn on delay is nearly independent of the input voltage.

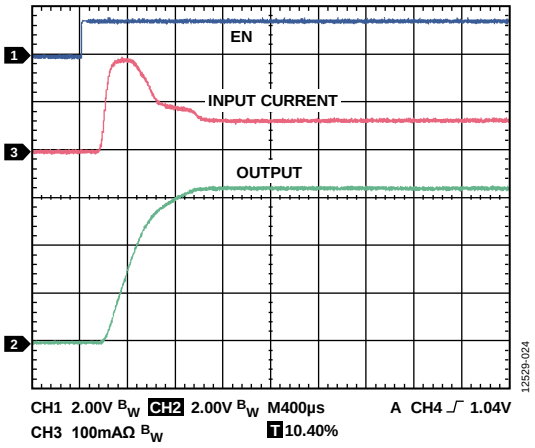


Figure 24. Typical Turn On Time and Inrush Current, V_{IN} = 2.5 V, C_{OUT} = 10 µF, R_{LOAD} = 100 Ω

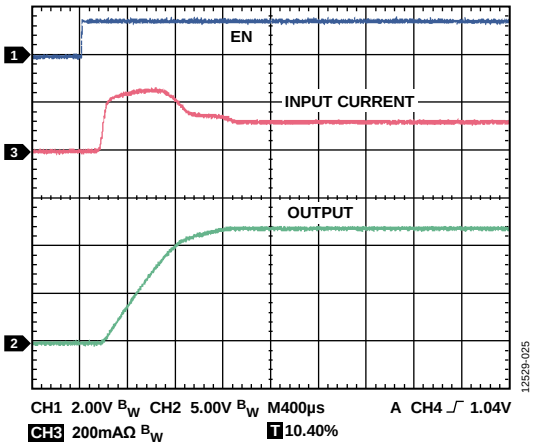


Figure 25. Typical Turn On Time and Inrush Current, V_{IN} = 6.5 V, C_{OUT} = 10 µF, R_{LOAD} = 100 Ω

The rise time is defined as the time it takes the output voltage to rise from 10% to 90% of V_{OUT} reaching its final value. The turn on delay is dependent on the rise time of the internal charge pump.

For very large values of output capacitance, the RC time constant (where C is the load capacitance, C_{LOAD}, and R is the $RDS_{ON}||R_{LOAD}$) can become a factor in the rise time of the output voltage. Because RDS_{ON} is much smaller than R_{LOAD}, an adequate approximation for RC is $RDS_{ON} \times C_{LOAD}$. An input or load capacitor is not required for the ADP1290; however, capacitors can suppress noise on the board.

The turn off time is defined as the time it takes for the output voltage to fall from 90% to 10% of V_{OUT} reaching its final value. The turn off time is also dependent on the RC time constant of the output capacitance (C_{LOAD}) and load resistance (R_{LOAD}).

Figure 26 and Figure 27 show the typical turn off times with V_{IN} = 6.5 V, C_{OUT} = 10 µF and 100 µF, and R_{LOAD} = 100 Ω.

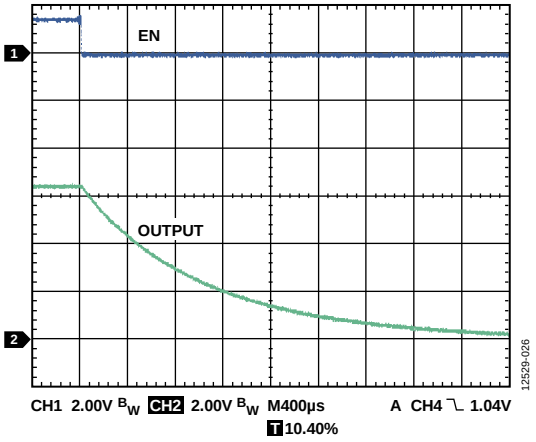


Figure 26. Typical Turn Off Time, C_{OUT} = 10 µF, R_{LOAD} = 100 Ω

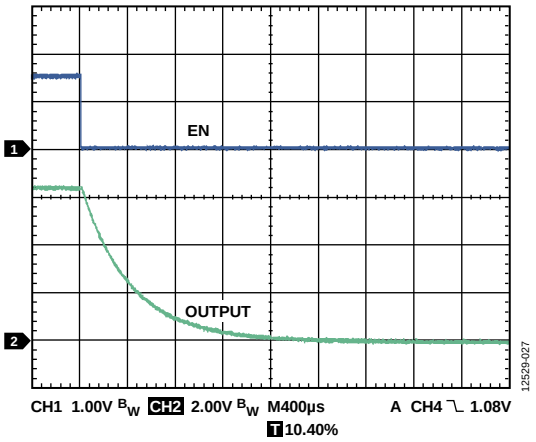


Figure 27. Typical Turn Off Time, C_{OUT} = 100 µF, R_{LOAD} = 100 Ω

CURRENT AND THERMAL OVERLOAD PRECAUTIONS

The ADP1290 is not protected against damage due to excessive power dissipation and does not have thermal overload protection circuits. To prevent permanent damage, never allow current through the ADP1290 to exceed its rated value for more than a few milliseconds. Permanent damage can also occur if the output is shorted to ground

THERMAL CONSIDERATIONS

To guarantee reliable operation, the junction temperature of the ADP1290 must not exceed 105°C. To ensure that the junction temperature stays below this maximum value, the user must be aware of the parameters that contribute to junction temperature changes. These parameters include ambient temperature, power dissipation in the power device, and thermal resistances between the junction and ambient air (θ_{JA}). The θ_{JA} number is dependent on the package assembly and the amount of copper used to solder the package pins to the PCB.

OUTLINE DIMENSIONS

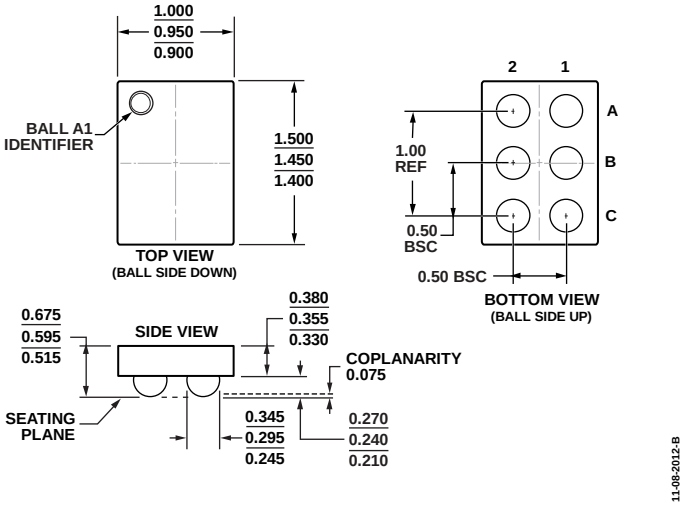


Figure 28. 6-Ball Wafer Level Chip Scale Package [WLCSP]
(CB-6-2)
Dimensions shown in millimeters

ORDERING GUIDE

Model[1]	Temperature Range	Package Description	Package Option	Branding
ADP1290ACBZ-R7	−40°C to +105°C	6-Ball Wafer Level Chip Scale Package [WLCSP]	CB-6-2	CL
ADP1290CB-EVALZ		Evaluation Board		

[1] Z = RoHS Compliant Part.

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